

# Standard Rectifier Module


<b>1~ Rectifier</b>
$V_{RRM} = 1600\text{ V}$
$I_{DAV} = 160\text{ A}$
$I_{FSM} = 2800\text{ A}$

## 1~ Rectifier Bridge

Part number

**VBO160-16NO7**



 E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: PWS-E

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

### Disclaimer Notice

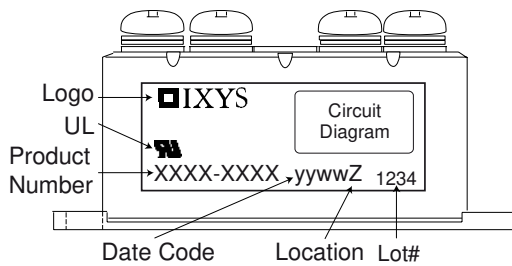
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Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					1700	V
$V_{RRM}$	max. repetitive reverse blocking voltage					1600	V
$I_R$	reverse current	$V_R = 1600\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		200	$\mu\text{A}$
		$V_R = 1600\text{ V}$		$T_{VJ} = 150^\circ\text{C}$		3.5	mA
$V_F$	forward voltage drop	$I_F = 160\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		1.07	V
		$I_F = 320\text{ A}$				1.22	V
		$I_F = 160\text{ A}$		$T_{VJ} = 125^\circ\text{C}$		0.96	V
		$I_F = 320\text{ A}$				1.15	V
$I_{DAV}$	bridge output current	$T_C = 110^\circ\text{C}$		$T_{VJ} = 150^\circ\text{C}$		160	A
		rectangular	$d = 0.5$				
$V_{FO}$	threshold voltage			$T_{VJ} = 150^\circ\text{C}$		0.74	V
$r_F$	slope resistance					2.4	m $\Omega$
						} for power loss calculation only	
$R_{thJC}$	thermal resistance junction to case					0.4	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.15		K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		310	W
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 45^\circ\text{C}$		2.80	kA
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		3.03	kA
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 150^\circ\text{C}$		2.38	kA
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		2.57	kA
$I^2t$	value for fusing	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 45^\circ\text{C}$		39.2	kA <sup>2</sup> s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		38.1	kA <sup>2</sup> s
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 150^\circ\text{C}$		28.3	kA <sup>2</sup> s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		27.5	kA <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$		133	pF



Package PWS-E				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$I_{RMS}$	RMS current	per terminal			250	A	
$T_{VJ}$	virtual junction temperature		-40		150	°C	
$T_{op}$	operation temperature		-40		125	°C	
$T_{stg}$	storage temperature		-40		125	°C	
<b>Weight</b>					273	g	
$M_D$	mounting torque		4.25		5.75	Nm	
$M_T$	terminal torque		4.25		5.75	Nm	
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	12.0			mm	
$d_{Spb/Apb}$		terminal to backside	26.0			mm	
$V_{ISOL}$	isolation voltage	t = 1 second	3000			V	
		t = 1 minute	2500			V	



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VBO160-16NO7	VBO160-16NO7	Box	5	491381

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 150^{\circ}C$

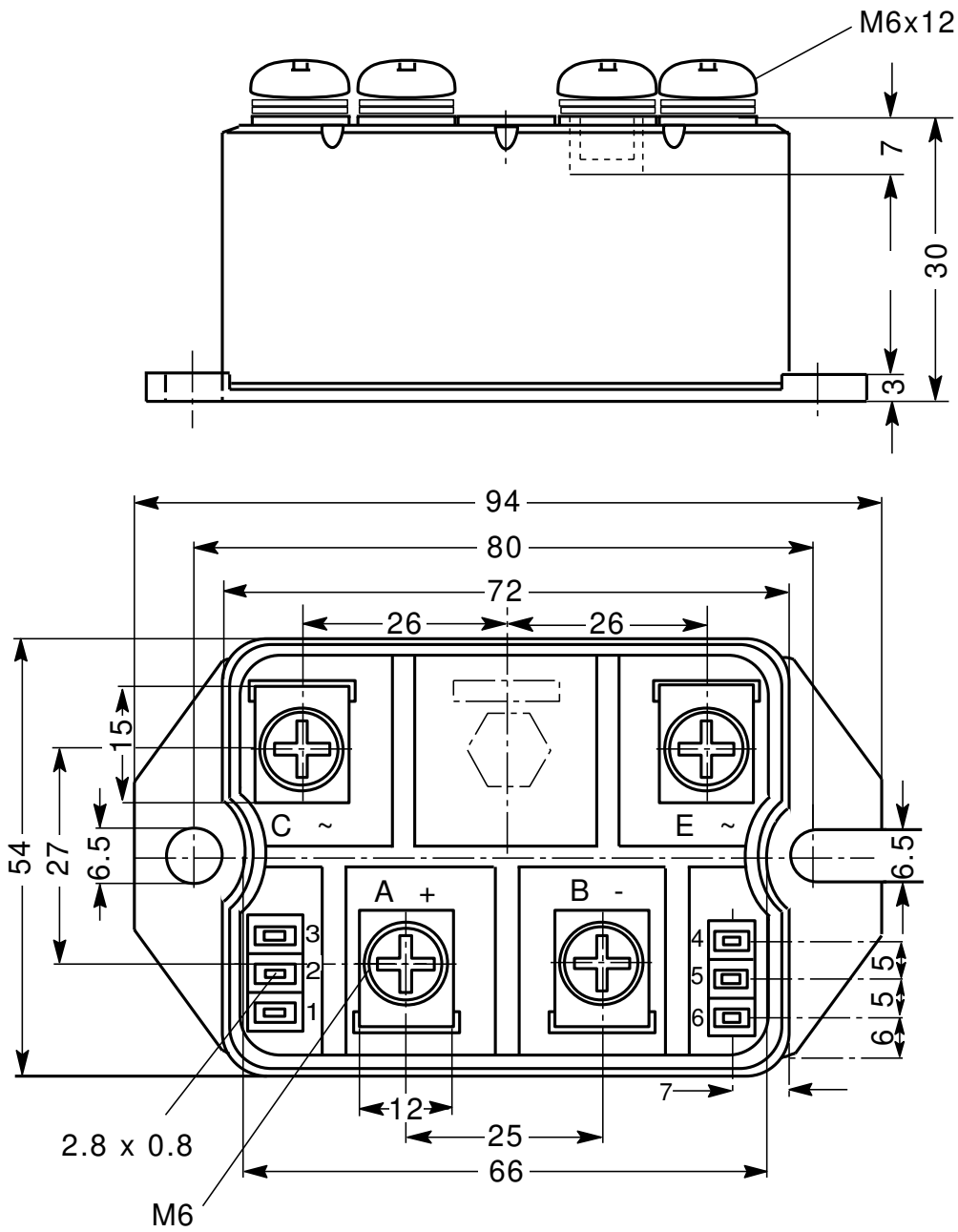


**Rectifier**

$V_{0\ max}$	threshold voltage	0.74	V
$R_{0\ max}$	slope resistance *	1.2	mΩ



Outlines PWS-E



**Rectifier**


Fig. 1 Forward current vs. voltage drop per diode

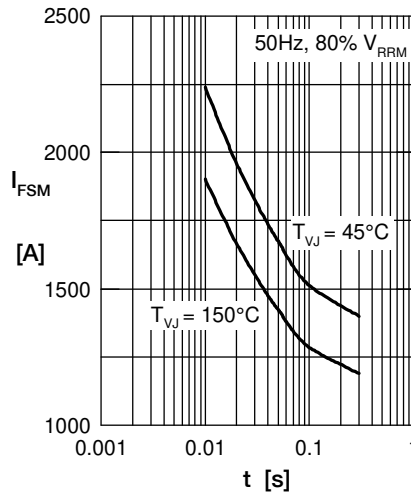


Fig. 2 Surge overload current vs. time per diode

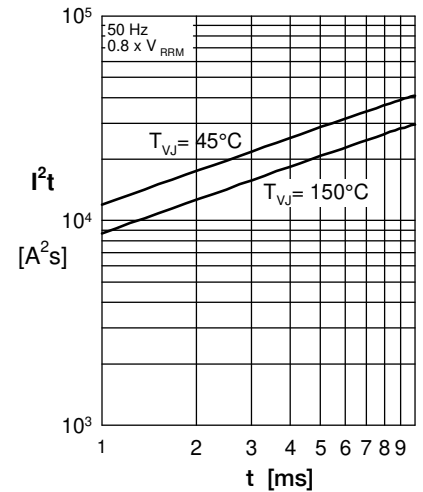
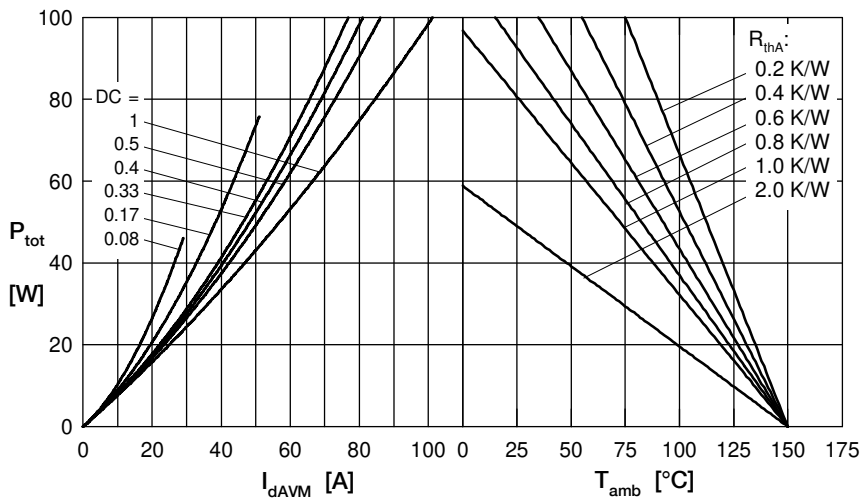

 Fig. 3  $I^2t$  vs. time per diode


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

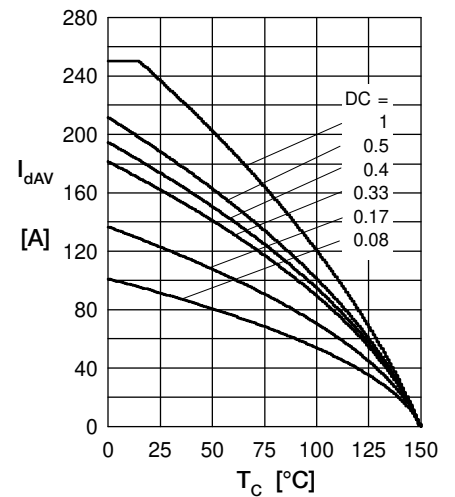


Fig. 5 Max. forward current vs. case temperature per diode

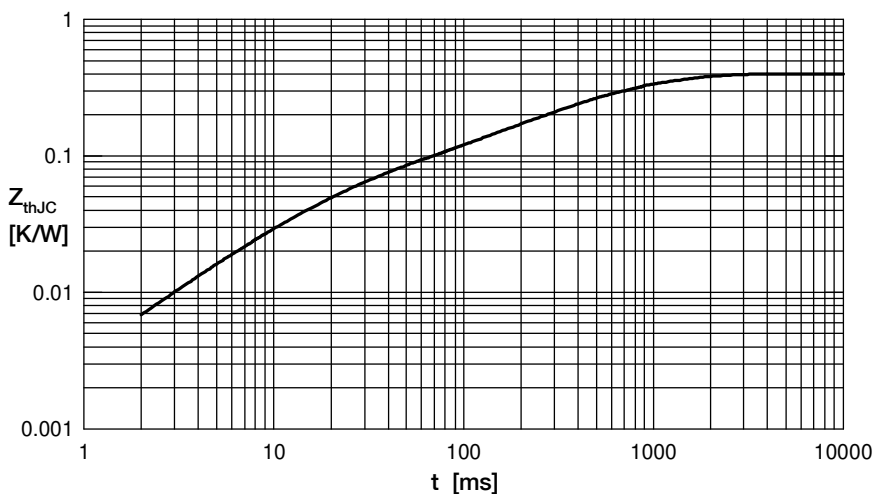


Fig. 6 Transient thermal impedance junction to case vs. time per diode

